

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	382	sacrificial same spacer same gate same pattern\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/19 11:24
L2	34	(SiN or "silicon nitride" or "hard mask") same spacer same gate same pattern\$4 same (polymer or polymeric)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/19 11:26
L3	2632	(SiN or "silicon nitride" or "hard mask") and spacer and gate and pattern\$4 and (polymer or polymeric)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/19 11:31
L4	367	3 and (sacrificial or removable)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/19 11:27
L5	58	((SiN or "silicon nitride") with sacrificial) and spacer and gate and pattern\$4 and (polymer or polymeric)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/19 11:32
L6	398	(SiN or "silicon nitride") with spacer with gate with pattern\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/19 11:39
L7	566	(SiN or "silicon nitride") with polymer\$3 with etch\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/19 12:13
L9	1	"5286344".PN.	USPAT; USOCR	OR	OFF	2005/08/19 12:04
L13	7	yoo-seung-jong.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/19 12:16

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L6	1	(" bottom wiring" and via and "non conductive" and (antireflect or "anti reflection" or ARC) and mask and damascene).clm.	US-PGPUB	OR	ON	2005/08/19 07:27
L7	7	keum-dong-yeal.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/19 07:28